PINGWEI ENTERPRISE

R1200 THRU R3000

0.5&0.2AMPS.HIGH VOLTAGE SILICON RECTIFIER

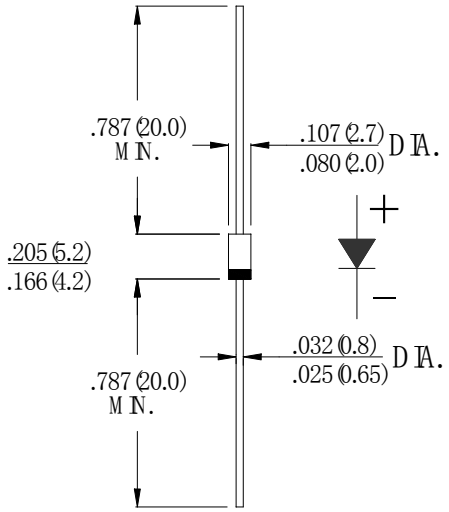
FEATURE

. High current capability
. Low forward voltage drop
. Low power loss, high efficiency
. High surge capability
. High voltage
. High temperature soldering guaranteed
260°C /10sec/ 0.375" lead length at 5 lbs tension

MECHANICAL DATA

. Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
. Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
. Polarity: color band denotes cathode
. Mounting position: any

DO-41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRONICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz,resistive or inductive load.
For capacitive load, derate current by 20%.

Type Number	SYMBOL	R1200	R1500	R1800	R2000	R2500	R3000	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1200	1500	1800	2000	2500	3000	V
Maximum RMS Voltage	V_{RMS}	840	1050	1260	1400	1750	2100	V
Maximum DC Blocking Voltage	V_{DC}	1200	1500	1800	2000	2500	3000	V
Maximum Average Forward rectified Current at T_A=50°C	$I_{F(AV)}$	0.5			0.2			A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}	30						A
Maximum Forward Voltage Drop per element at 0.5/0.2A DC	V_F	2.0			3.0		4.0	V
Maximum DC Reverse Current @T_A=25°C	I_R	5.0						μA
at rated DC blocking voltage @T_A =100°C		500						
Maximum Full Load Reverse Current Average, Full Cycle .375"(9.5mm) lead length at T_L=55°C		30						
Typical Junction Capacitance (Note)	C_J	30						pF
Storage Temperature	T_{STG}	-55 to +150						°C
Operation Junction Temperature	T_J	-55 to +125						°C